

TOSHIBA**TC74ACT161,163P/F/FN**

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

**TC74ACT161P, TC74ACT161F, TC74ACT161FN
TC74ACT163P, TC74ACT163F, TC74ACT163FN**
SYNCHRONOUS PRESETTABLE 4-BIT BINARY COUNTER
TC74ACT161P/F/FN ASYNCHRONOUS CLEAR
TC74ACT163P/F/FN SYNCHRONOUS CLEAR

(Note) The JEDEC SOP (FN) is not available in Japan.

The TC74ACT161 and T163 are advanced high speed CMOS SYNCHRONOUS PRESETTABLE 4 BIT BINARY COUNTERs fabricated with silicon gate and double-layer metal wiring C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

These devices may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

The CK input is active on the rising edge. Both LOAD and CLR inputs are active on low logic level.

Presetting of these IC's is synchronous to the rising edge of CK.

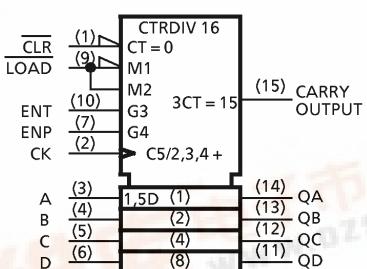
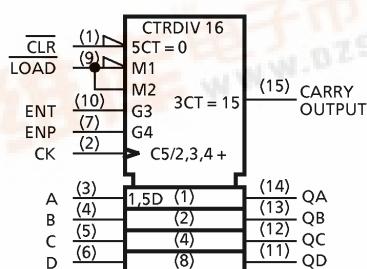
The clear function of the TC74ACT163 is synchronous to CK, while the TC74ACT161 are cleared asynchronously.

Two enable inputs (ENP and ENT) and CARRY OUTPUT are provided to enable easy cascading of counters, which facilitates easy implementation of n-bit counters without using external gates.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES:

- High Speed $f_{MAX} = 110\text{MHz}$ (typ.) at $V_{CC} = 5\text{V}$
- Low Power Dissipation $I_{CC} = 8\mu\text{A}$ (Max.) at $T_a = 25^\circ\text{C}$
- Compatible with TTL outputs ... $V_{IL} = 0.8\text{V}$ (Max.)
 $V_{IH} = 2.0\text{V}$ (Min.)
- Symmetrical Output Impedance... $|I_{OH}| = |I_{OL}| = 24\text{mA}$ (Min.)
Capability of driving 50Ω transmission lines.
- Balanced Propagation Delays..... $t_{PLH} \approx t_{PHL}$
- Pin and Function Compatible with 74F161 / 163

IEC LOGIC SYMBOL**TC74ACT161****TC74ACT163**

● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

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TRUTH TABLE

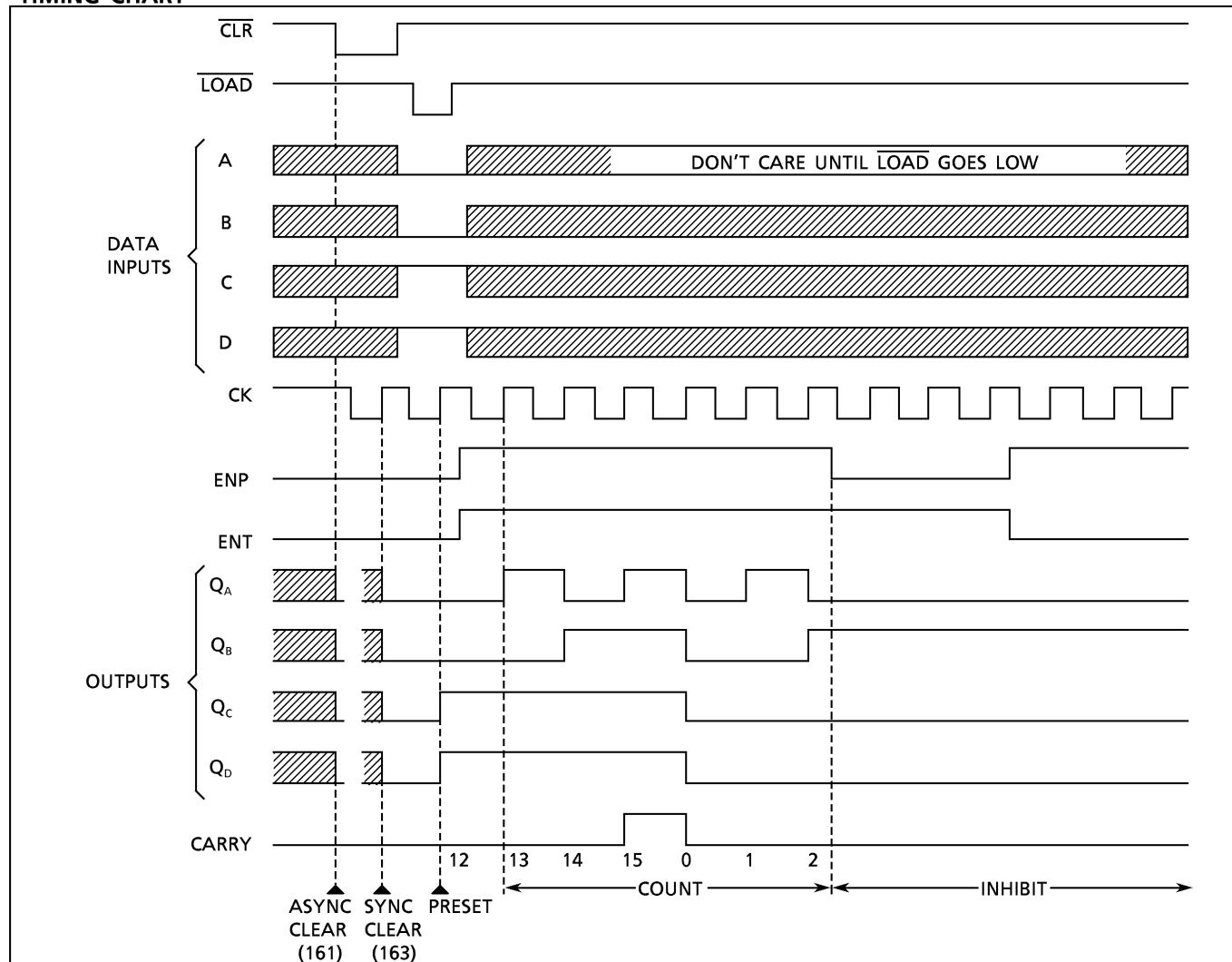
INPUTS							OUTPUTS				FUNCTION
CLR (161)	CLR (163)	LOAD	ENP	ENT	CK (161)	CK (163)	QA	QB	QC	QD	FUNCTION
L	L	X	X	X	X	↑	L	L	L	L	RESET TO "0"
H	H	L	X	X	↑	↑	A	B	C	D	PRESET DATA
H	H	H	X	L	↑	↑	NO CHANGE				NO COUNT
H	H	H	L	X	↑	↑	NO CHANGE				NO COUNT
H	H	H	H	H	↑	↑	COUNT UP				COUNT
H	X	X	X	X	↓	↓	NO CHANGE				NO COUNT

Note X : Don't Care

A, B, C, D : Logic Level of Data Inputs

Carry : CARRY = ENT · QA · QB · QC · QD

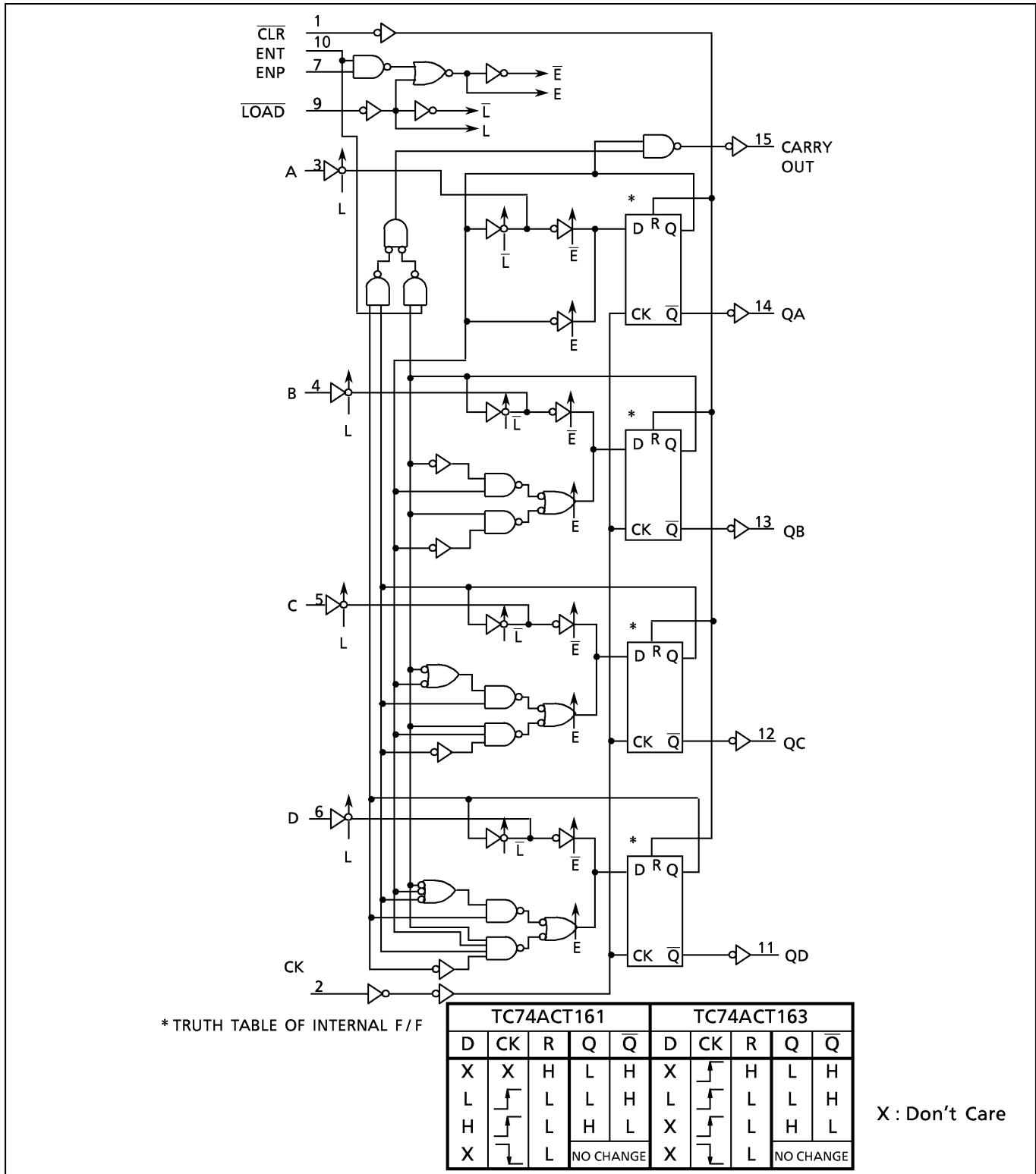
TIMING CHART



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- The information contained herein is subject to change without notice.

SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~ $V_{CC} + 0.5$	V
DC Output Voltage	V_{OUT}	-0.5~ $V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 50	mA
DC Output Current	I_{OUT}	± 50	mA
DC V_{CC} /Ground Current	I_{CC}	± 125	mA
Power Dissipation	P_D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T_{STG}	-65~150	°C

*500mW in the range of $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$. From $T_a = 65^{\circ}\text{C}$ to 85°C a derating factor of $-10\text{mW}/^{\circ}\text{C}$ should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	4.5~5.5	V
Input Voltage	V_{IN}	0~ V_{CC}	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	dt/dV	0~10	ns/V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V_{IH}		4.5 5.5	2.0	—	—	2.0	—	V
Low - Level Input Voltage	V_{IL}		4.5 5.5	—	—	0.8	—	0.8	V
High - Level Output Voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50\mu\text{A}$ $I_{OH} = -24\text{mA}$ $I_{OH} = -75\text{mA}^*$	4.5 4.5 5.5	4.4 3.94 —	4.5 — —	— — —	4.4 3.80 3.85	— — —
Low - Level Output Voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50\mu\text{A}$ $I_{OL} = 24\text{mA}$ $I_{OL} = 75\text{mA}^*$	4.5 4.5 5.5	— — —	0.0 0.36 —	0.1 — —	0.1 0.44 1.65	V
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC}$ or GND	5.5	—	—	± 0.1	—	± 1.0	μA
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND	5.5	—	—	8.0	—	80.0	
	I_C	PER INPUT : $V_{IN} = 3.4\text{V}$ OTHER INPUT : V_{CC} or GND	5.5	—	—	1.35	—	1.5	mA

* : This spec indicates the capability of driving 50Ω transmission lines.

One output should be tested at a time for a 10ms maximum duration.

TIMING REQUIREMENTS (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	T _a = 25°C	T _a = -40~85°C	UNIT
				LIMIT	LIMIT	
Minimum Pulse Width (CK)	$t_W(L)$ $t_W(H)$	Fig .1	5.0 ± 0.5	5.0	5.0	ns
Minimum Pulse Width (\overline{CLR})*	$t_W(L)$	Fig .4	5.0 ± 0.5	5.0	5.0	
Minimum Pulse Width (LOAD, ENP, ENT)	t_s	Fig .2, 3	5.0 ± 0.5	6.0	6.0	
Minimum Set - up Time (A, B, C, D)	t_s	Fig .2	5.0 ± 0.5	4.0	4.0	
Minimum Set - up Time (\overline{CLR})**	t_s	Fig .5	5.0 ± 0.5	3.0	3.0	
Minimum Hold Time (LOAD, ENP, ENT)	t_h	Fig .2, 3	5.0 ± 0.5	1.0	1.0	
Minimum Hold Time (A, B, C, D)	t_h	Fig .2	5.0 ± 0.5	2.0	2.0	
Minimum Hold Time (\overline{CLR})**	t_h	Fig .5	5.0 ± 0.5	2.0	2.0	
Minimum Removal Time (\overline{CLR})*	t_{rem}	Fig .4	5.0 ± 0.5	1.0	1.0	

* for TC74ACT161 only

** for TC74ACT163 only

AC ELECTRICAL CHARACTERISTICS (CL = 50pF, RL = 500 Ω, Input tr = tf = 3ns)

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C			Ta = - 40~85°C		UNIT
			V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	
Propagation Delay Time (CK-Q)	t _{pLH} t _{pHL}	Fig.1	5.0 ± 0.5	—	7.2	10.5	1.0	12.0
Propagation Delay Time (CK-CARRY, Count Mode)	t _{pLH} t _{pHL}		5.0 ± 0.5	—	8.5	13.0	1.0	15.0
Propagation Delay Time (CK-CARRY, Preset Mode)	t _{pLH} t _{pHL}		5.0 ± 0.5	—	9.7	15.0	1.0	17.0
Propagation Delay Time (ENT-CARRY)	t _{pLH} t _{pHL}		5.0 ± 0.5	—	6.6	10.0	1.0	11.5
Propagation Delay Time (CLR-Q)*	t _{pHL}		5.0 ± 0.5	—	6.3	10.0	1.0	11.5
Propagation Delay Time (CLR-CARRY)*	t _{pHL}		5.0 ± 0.5	—	7.7	12.3	1.0	14.0
Maximum Clock Frequency	f _{MAX}		5.0 ± 0.5	70	100	—	60	—
Input Capacitance	C _{IN}			—	5	10	—	10
Power Dissipation Capacitance	C _{PD} (1)			—	46	—	—	—

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr.}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

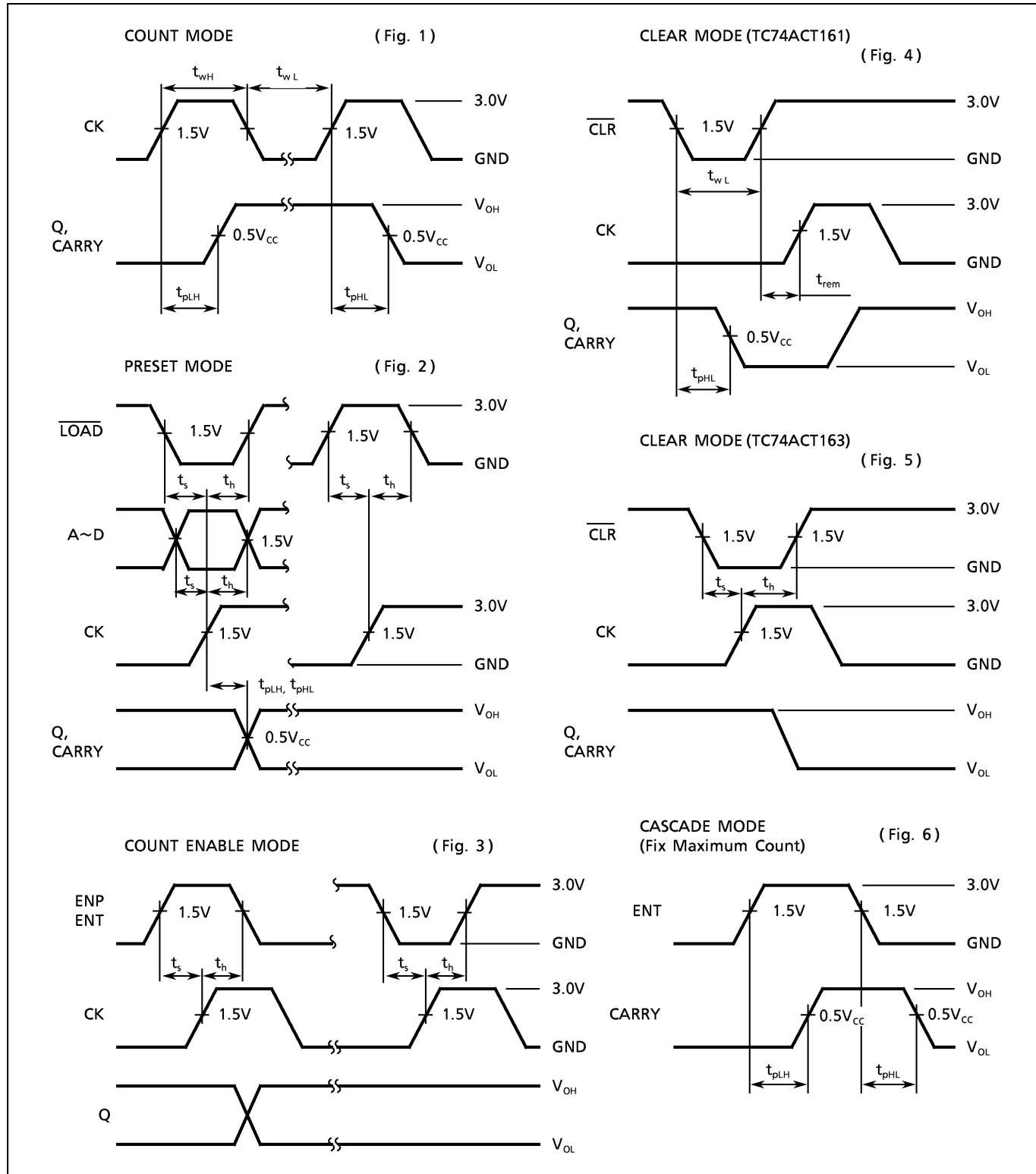
When the outputs drive a capacitive load, total current consumption is the sum of C_{PD}, and ΔI_{CC} which is obtained from the following formula:

$$\Delta I_{CC} = f_{CK} \cdot V_{CC} \left(\frac{C_{QA}}{2} + \frac{C_{QB}}{4} + \frac{C_{QC}}{8} + \frac{C_{QD}}{16} + \frac{C_{CO}}{16} \right)$$

C_{QA}~C_{QD} and C_{CO} are the capacitances at QA~QD and CARRY OUT, respectively.
f_{CK} is the input frequency of the CK.

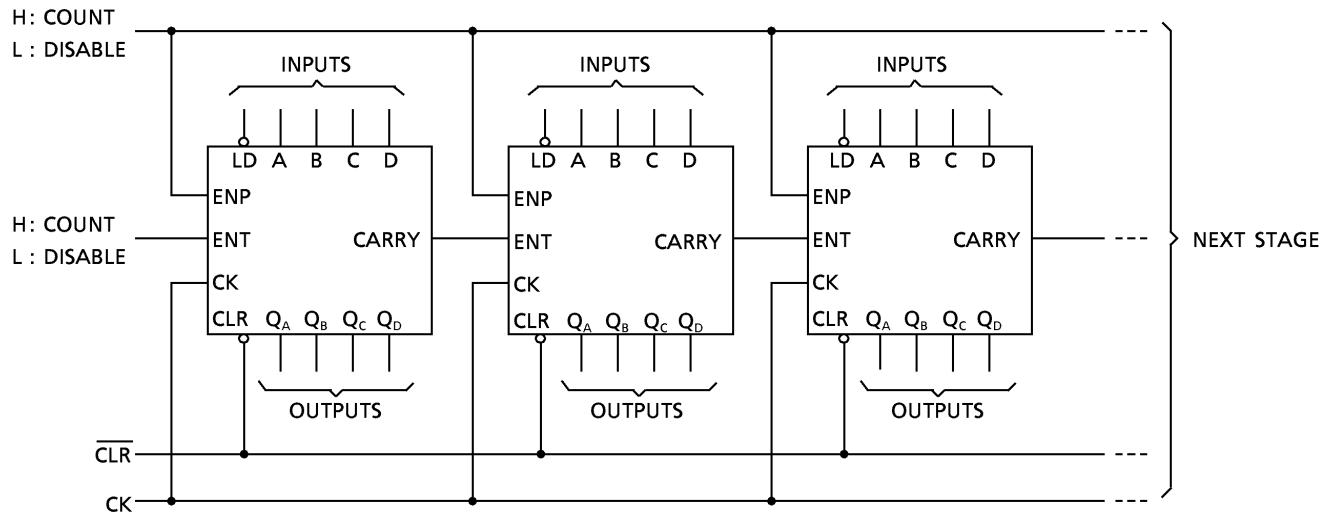
(2) * for TC74ACT161 only

SWITCHING CHARACTERISTICS TEST WAVEFORM



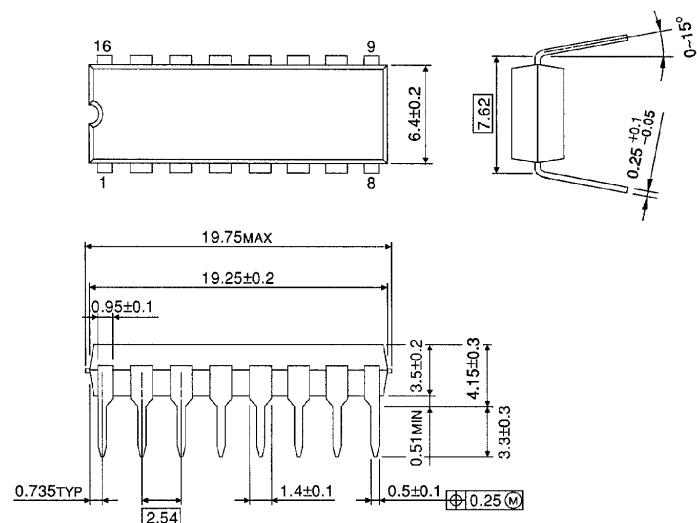
TYPICAL APPLICATION

PARALLEL CARRY N-BIT COUNTER



DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A)

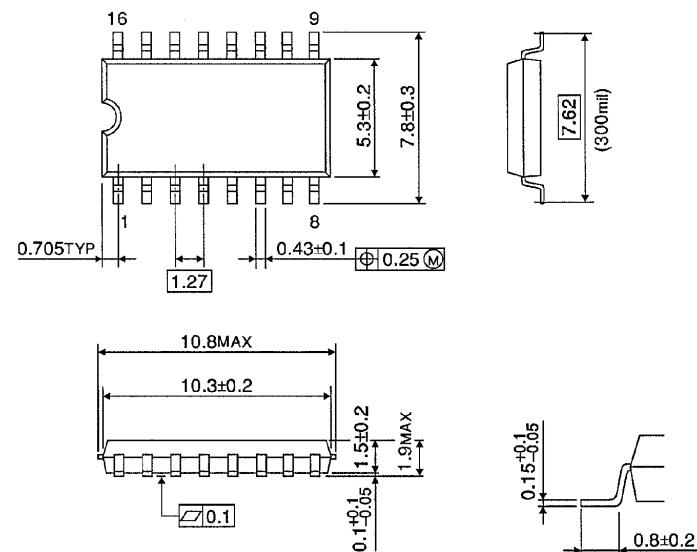
Unit in mm



Weight : 1.00g (Typ.)

SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27)

Unit in mm

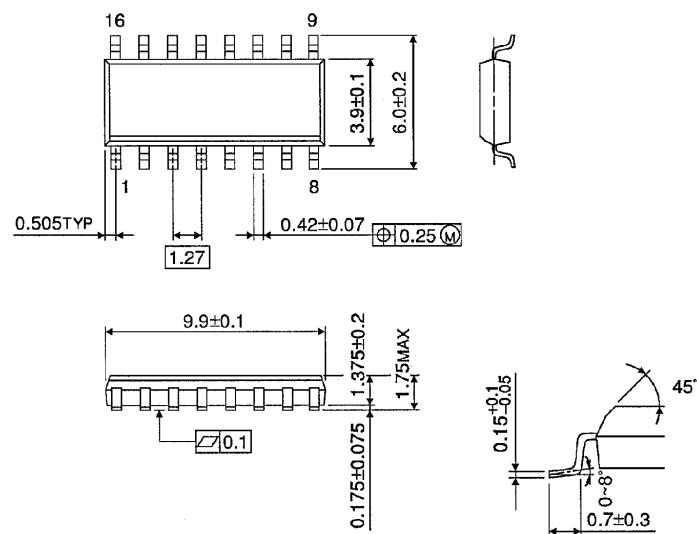


Weight : 0.18g (Typ.)

SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16-P-150 -1.27)

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)